





SN74LV374A SCLS408L - MAY 1998 - REVISED MARCH 2023

SN74LV374A Octal Edge-Triggered D-Type Flip-Flops With 3-State Outputs

## 1 Features

Texas

 $V_{CC}$  operation of 2 V to 5.5 V

INSTRUMENTS

- Maximum  $t_{\text{pd}}$  of 9.5 ns at 5 V
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at  $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) >2.3 V at  $V_{CC} = 3.3 \text{ V}, \text{ T}_{A} = 25^{\circ}\text{C}$
- Support Mixed-Mode Voltage Operation on All Ports
- Ioff Supports Partial-Power-Down Mode Operation
- Latch-up Performance Exceeds 250 mA Per JESD 17

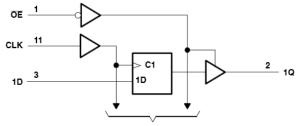
## 2 Applications

- Programmable Logic Controller (PLC)
- DCS and PAC: Analog Input Module
- Trains, Trams, and Subway Carriages •
- **AC Inverter Drives** •
- Printers

## **3 Description**

The SN74LV374A devices are octal edge-triggered Dtype flip-flops designed for 2 V to 5.5 V  $V_{CC}$  operation.

Package Information									
PART NUMBER	PACKAGE	BODY SIZE (NOM)							
	DB (SSOP, 20)	7.20 mm × 5.30 mm							
SN74LV374A	DW (SOIC, 20)	12.80 mm × 7.50 mm							
SIN/4LV3/4A	NS (SO, 20)	12.60 mm × 5.30 mm							
	PW (TSSOP, 20)	6.50 mm × 4.40 mm							



To Seven Other Channels

Pin numbers shown are for the DB, DW, NS, PW, and RGY packages

### Logic Diagram (Positive Logic)





## **Table of Contents**

1 Features1	8 Detailed Description	10
2 Applications1	8.1 Overview	
3 Description1	8.2 Functional Block Diagram	10
4 Revision History2	8.3 Feature Description	
5 Pin Configuration and Functions	8.4 Device Functional Modes	
6 Specifications4	9 Application and Implementation	11
6.1 Absolute Maximum Ratings4	9.1 Application Information	.11
6.2 ESD Ratings4	9.2 Typical Application	11
6.3 Recommended Operating Conditions5	9.3 Power Supply Recommendations	12
6.4 Thermal Information5	9.4 Layout	12
6.5 Electrical Characteristics6	10 Device and Documentation Support	14
6.6 Switching Characteristics, $V_{CC} = 2.5 V \pm 0.2 V$ 6	10.1 Documentation Support	14
6.7 Switching Characteristics, V <sub>CC</sub> = 3.3 V ± 0.3 V7	10.2 Receiving Notification of Documentation Updates.	14
6.8 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$ 7	10.3 Support Resources	14
6.9 Timing Requirements7	10.4 Trademarks	14
6.10 Noise Characteristics8	10.5 Electrostatic Discharge Caution	14
6.11 Operating Characteristics, T <sub>A</sub> = 25°C8	10.6 Glossary	14
6.12 Typical Characteristics8	11 Mechanical, Packaging, and Orderable	
7 Parameter Measurement Information	Information	15

### **4 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision K (December 2022) to Revision L (March 2023)	Page
Updated structural layout of document and format of tables	1
• Updated thermal values for DW package from RθJA = 79.2 to 102.3, RθJC(top) = 4	43.7 to 69.9, RθJB = 47 to
70.8, ΨJT =18.6 to 46.4, ΨJB = 46.5 to 70.4, all values in °C/W	5
Changes from Revision J (March 2015) to Revision K (December 2022)	Page
Updated the format for tables, figures, and cross-references throughout the docum	ent1
Changes from Revision I (March 2015) to Revision J (October 2016)	Page
Added Junction temperature, T <sub>J</sub>	
• Deleted " $V_{CC} \times 0.3$ " from MIN and added " $V_{CC} \times 0.3$ " to MAX for SN54LV374A and	SN74LV374A5
Changed "SN54LV384A" to "SN54LV374A" in Electrical Characteristics table	6
Added Related Links section, Receiving Notification of Documentation Updates sec	ction, and Community
Resources section	
Changes from Revision H (April 2005) to Revision I (March 2015)	Page
Added Pin Configuration and Functions section. ESD Ratings table. Feature Descr	iption section. Device

 Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section



## **5** Pin Configuration and Functions

OE [	1	υ	20	Vcc
1Q 🛛	2		19	] 8Q
1D [	3		18	] 8D
2D 🛛	4		17	]7D
2Q [	5		16	]7Q
3Q [	6		15	] 6Q
3D 🛛	7		14	] 6D
4D 🛛	8		13	5D
4Q [	9		12	] 5Q
GND [	10		11	] сгк

## Figure 5-1. DB, DW, NS, or PW Package 20-PIN SSOP, SOIC, SO, or TSSOP (Top View)

P	PIN	TYDE	DESCRIPTION
NAME	NO.	TYPE	DESCRIPTION
ŌE	1	I	Enable pin
1Q	2	0	Output 1
1D	3	I	Input 1
2D	4	I	Input 2
2Q	5	0	Output 2
3Q	6	0	Output 3
3D	7	I	Input 3
4D	8	I	Input 4
4Q	9	0	Output 4
GND	10	_	Ground pin
CLK	11	I	Clock pin
5Q	12	0	Output 5
5D	13	I	Input 5
6D	14	I	Input 6
6Q	15	0	Output 6
7Q	16	0	Output 7
7D	17	I	Input 7
8D	18	I	Input 8
8Q	19	0	Output 8
V <sub>CC</sub>	20	_	Power pin

#### Table 5-1. Pin Functions



## 6 Specifications 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		-0.5	7	V
VI	Input voltage <sup>(2)</sup>		-0.5	7	V
Vo	Voltage applied to any output in	n the high-impedance or power-off state <sup>(2)</sup>	-0.5	7	V
Vo	Output voltage <sup>(2) (3)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	(V <sub>1</sub> < 0)		-20	mA
I <sub>OK</sub>	Output clamp current	(V <sub>O</sub> < 0)		-50	mA
I <sub>O</sub>	Continuous output current	$(V_{O} = 0 \text{ to } V_{CC})$		±35	mA
	Continuous current through V <sub>C</sub>	<sub>C</sub> or GND		±70	mA
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) This value is limited to 5.5 V maximum.

### 6.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000	V
		Machine Model (A115-A)	±200	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



## **6.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted) (1)

			SN74LV3	74A	
			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2	5.5	V
		V <sub>CC</sub> = 2 V	1.5		
		V <sub>CC</sub> = 2.3 V to 2.7 V	V <sub>CC</sub> × 0.7		V
VIH	High-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V	V <sub>CC</sub> × 0.7		v
		V <sub>CC</sub> = 4.5 V to 5.5 V	V <sub>CC</sub> × 0.77		
		V <sub>CC</sub> = 2 V		0.5	
		V <sub>CC</sub> = 2.3 V to 2.7 V		V <sub>CC</sub> × 0.3	V
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V		V <sub>CC</sub> × 0.3	
		V <sub>CC</sub> = 4.5 V to 5.5 V		V <sub>CC</sub> × 0.3	
VI	Input voltage	I	0	5.5	V
	Output voltage	High or low state	0	V <sub>CC</sub>	
Vo		3-state	0	5.5	V
		V <sub>CC</sub> = 2 V		-50	μA
		V <sub>CC</sub> = 2.3 V to 2.7 V		-2	
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 3 V to 3.6 V		-8	mA
		V <sub>CC</sub> = 4.5 V to 5.5 V		-16	
		V <sub>CC</sub> = 2 V		50	μA
		V <sub>CC</sub> = 2.3 V to 2.7 V		2	
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 3 V to 3.6 V		8	mA
		V <sub>CC</sub> = 4.5 V to 5.5 V		16	
		V <sub>CC</sub> = 2.3 V to 2.7 V		200	
Δt/Δv	Input transition rise or fall rate	V <sub>CC</sub> = 3 V to 3.6 V		100	ns/V
		V <sub>CC</sub> = 4.5 V to 5.5 V		20	
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

 All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. See *Implications of Slow or Floating* CMOS Inputs, SCBA004.

#### 6.4 Thermal Information

			SN74LV	/374A			
THERMAL METRIC <sup>(1)</sup>		THERMAL METRIC <sup>(1)</sup> DB (SSOP) DW (SOIC)					
		20 PINS	20 PINS	20 PINS	20 PINS		
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	94.5	102.3	76.7	102.4	°C/W	
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	56.4	69.9	43.2	36.5	°C/W	
R <sub>θJB</sub>	Junction-to-board thermal resistance	49.7	70.8	44.2	53.6	°C/W	
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	18.5	46.4	16.8	2.4	°C/W	
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	49.3	70.4	43.8	52.9	°C/W	
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	°C/W	

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.



### **6.5 Electrical Characteristics**

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>		LV374A to +85°C	-	174LV374A C to +125°C		UNIT
			MIN	TYP MAX	MIN	TYP	MAX	
	I <sub>OH</sub> = -50 μA	2 V to 5.5 V	V <sub>CC</sub> -0.1		V <sub>CC</sub> -0.1			
	I <sub>OH</sub> = −2 mA	2.3 V	2		2			v
V <sub>OH</sub>	I <sub>OH</sub> =8 mA	3 V	2.48		2.48			v
	I <sub>OH</sub> = −16 mA	4.5 V	3.8		3.8			
	I <sub>OL</sub> = 50 μA	2 V to 5.5 V		0.1			0.1	
	I <sub>OL</sub> = 2 mA	2.3 V		0.4			0.4	v
V <sub>OL</sub>	I <sub>OL</sub> = 8 mA	3 V		0.44			0.44	v
	I <sub>OL</sub> = 16 mA	4.5 V		0.55			0.55	
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	0 to 5.5 V		±1			±1	μA
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	5.5 V		±5			±5	μA
I <sub>CC</sub>	$V_{I} = V_{CC}$ or GND , $I_{O} = 0$	5.5 V		20			20	μA
I <sub>off</sub>	$V_{\rm I}$ or $V_{\rm O}$ = 0 to 5.5 V	0		Ę			5	μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V		2.9		2.9		pF

over recommended operating free-air temperature range (unless otherwise noted)

## 6.6 Switching Characteristics, V<sub>CC</sub> = 2.5 V $\pm$ 0.2 V

over recommended operating free-air temperature range,  $V_{CC}$  = 2.5 V ± 0.2 V (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T <sub>A</sub> = 25°C		T <sub>A</sub> = 25°C		T <sub>A</sub> = 25°C		374A +85°C	SN74LV3 –40°C to +		UNIT
	(INPUT)	(001201)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX			
£			C <sub>L</sub> = 15 pF	60 <sup>(1)</sup>	105 <mark>(1)</mark>		50		50		MHz		
f <sub>max</sub>			C <sub>L</sub> = 50 pF	50	85		40		40		MHZ		
t <sub>pd</sub>	CLK	Q			9.7 <sup>(1)</sup>	16.3 <mark>(1)</mark>	1	19	1	20.5			
t <sub>en</sub>	ŌĒ	Q	C <sub>L</sub> = 15 pF		8.9 <mark>(1)</mark>	15.9 <mark>(1)</mark>	1	19	1	20.5	ns		
t <sub>dis</sub>	ŌĒ	Q			6.3 <sup>(1)</sup>	12.6 <mark>(1)</mark>	1	15	1	16.5			
t <sub>pd</sub>	CLK	Q			11.8	19.3	1	23	1	24.5			
t <sub>en</sub>	ŌĒ	Q	0 - 50 - 5		10.9	18.8	1	22	1	23.5			
t <sub>dis</sub>	ŌĒ	Q	C <sub>L</sub> = 50 pF		8.2	17.3	1	19	1	20.5	ns		
t <sub>sk(o)</sub>						2		2					

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.



## 6.7 Switching Characteristics, V<sub>CC</sub> = 3.3 V $\pm$ 0.3 V

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T <sub>A</sub> = 25°C		T <sub>A</sub> = 25°C			T <sub>A</sub> = 25°C		T <sub>A</sub> = 25°C		SN74LV374A -40°C to +85°C		SN74LV374A –40°C to +125°C	
		(001F01)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX						
f			C <sub>L</sub> = 15 pF	80 <sup>(1)</sup>	150 <sup>(1)</sup>		70		70		MHz					
f <sub>max</sub>			C <sub>L</sub> = 50 pF	55	110		50		50		IVITIZ					
t <sub>pd</sub>	CLK	Q			6.8 <sup>(1)</sup>	12.7 <mark>(1)</mark>	1	15	1	16						
t <sub>en</sub>	ŌE	Q	C <sub>L</sub> = 15 pF		6.3 <sup>(1)</sup>	11 <mark>(1)</mark>	1	13	1	14	ns					
t <sub>dis</sub>	ŌĒ	Q			4.7 <sup>(1)</sup>	10.5 <mark>(1)</mark>	1	12.5	1	13.5						
t <sub>pd</sub>	CLK	Q			8.3	16.2	1	18.5	1	19.5						
t <sub>en</sub>	ŌĒ	Q	C = 50  pc		7.7	14.5	1	16.5	1	17.5	20					
t <sub>dis</sub>	ŌĒ	Q	C <sub>L</sub> = 50 pF		5.9	14	1	16	1	17	ns					
t <sub>sk(o)</sub>						1.5		1.5								

over recommended operating free-air temperature range,  $V_{CC}$  = 3.3 V ± 0.3 V (unless otherwise noted)

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

#### 6.8 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range,  $V_{CC}$  = 5 V ± 0.5 V (unless otherwise noted)

PARAMETER	FROM TO (INPUT) (OUTPUT)		LOAD CAPACITANCE	T <sub>A</sub> = 25°C			SN74LV -40°C to	-	SN74L –40°C to	UNIT	
			CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
£			C <sub>L</sub> = 15 pF	130 <sup>(1)</sup>	205 <sup>(1)</sup>		110		110		MHz
f <sub>max</sub>			C <sub>L</sub> = 50 pF	85	1705		75		75		INITIZ
t <sub>pd</sub>	CLK	Q			4.9 <sup>(1)</sup>	8.1 <mark>(1)</mark>	1	9.5	1	10.5	
t <sub>en</sub>	ŌĒ	Q	C <sub>L</sub> = 15 pF		4.6 <sup>(1)</sup>	7.6 <mark>(1)</mark>	1	9	1	10	ns
t <sub>dis</sub>	ŌĒ	Q			3.4 <sup>(1)</sup>	6.8 <mark>(1)</mark>	1	8	1	9	
t <sub>pd</sub>	CLK	Q			5.9	10.1	1	11.5	1	12.5	
t <sub>en</sub>	ŌĒ	Q			5.5	9.6	1	11	1	12	
t <sub>dis</sub>	ŌĒ	Q	C <sub>L</sub> = 50 pF		4	8.8	1	10	1	11	ns
t <sub>sk(o)</sub>						1		1			

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

### 6.9 Timing Requirements

over recommended operating free-air temperature range, (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

		T <sub>A</sub> = 25°C	SN74LV374A -40°C to +85°	-	SN74LV374A -40°C to +125°C	
		MIN M	AX MIN	MAX MIN	MIN MAX	
V <sub>cc</sub> =	2.5 V ± 0.2 V		ц	I		
tw	Pulse duration, CLK high or low	6	7	7		ns
t <sub>su</sub>	Setup time, data before CLK↑	5	5.5	6		ns
t <sub>h</sub>	Hold time, data after CLK↑	2.5	2.5	3		ns
V <sub>cc</sub> =	3.3 V ± 0.3 V		U	I		
tw	Pulse duration, CLK high or low	5	5.5	5.5		ns
t <sub>su</sub>	Setup time, data before CLK↑	4.5	4.5	5		ns
t <sub>h</sub>	Hold time, data after CLK↑	2	2	2.5		ns
V <sub>cc</sub> =	5 V ± 0.5 V			I		
tw	Pulse duration, CLK high or low	5	5	5		ns
t <sub>su</sub>	Setup time, data before CLK↑	3	3	3.5		ns
t <sub>h</sub>	Hold time, data after CLK↑	2	2	2.5		ns



#### 6.10 Noise Characteristics

 $V_{CC}$  = 3.3 V,  $C_{L}$  = 50 pF,  $T_{A}$  = 25°C <sup>(1)</sup>

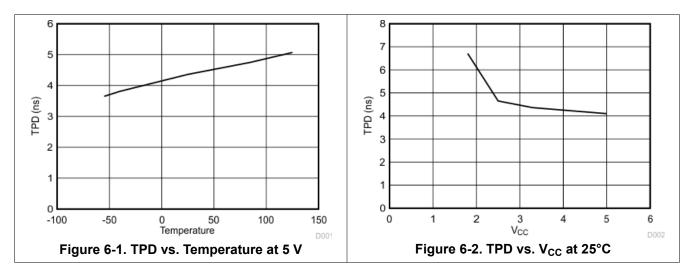
	PARAMETER	SN7	UNIT		
	PARAMETER	MIN	TYP	MAX	UNIT
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		0.6	0.8	V
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>		-0.5	-0.8	V
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>	2.9	2.9		V
V <sub>IH(D)</sub>	High-level dynamic input voltage	2.31			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.99	V

(1) Characteristics are for surface-mount packages only.

### 6.11 Operating Characteristics, T<sub>A</sub> = 25°C

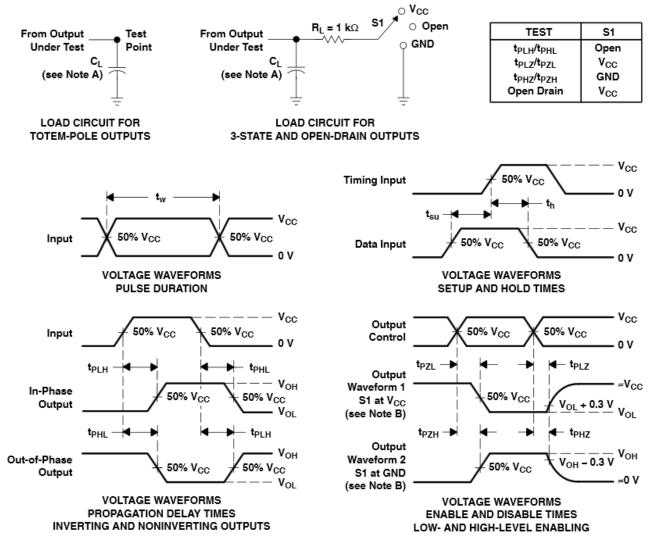
	PARAMETER		TEST CON	IDITIONS	V <sub>cc</sub>	TYP	UNIT
C	Power dissipation	Outputs enabled	$C_{1} = 50 \text{ pF}$	f = 10 MHz	3.3 V	21.1	рĘ
Cpd	capacitance	Outputs enabled	C <sub>L</sub> = 50 pF,		5 V	22.8	рг

## 6.12 Typical Characteristics





### 7 Parameter Measurement Information



- NOTES: A. CL includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  3 ns, t<sub>f</sub>  $\leq$  3 ns. D. The outputs are measured one at a time, with one input transition per measurement.

  - E. tpLz and tpHz are the same as tdis.
  - F. tpzL and tpzH are the same as ten.
  - G. t<sub>PHL</sub> and t<sub>PLH</sub> are the same as t<sub>pd</sub>.
  - H. All parameters and waveforms are not applicable to all devices.

#### Figure 7-1. Load Circuit and Voltage Waveforms



## 8 Detailed Description

#### 8.1 Overview

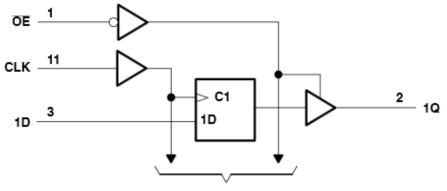
The SN74LV374A devices are octal edge-triggered D-type flip-flops designed for 2 V to 5.5 V  $V_{CC}$  operation. These devices feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bi-directional bus drivers, and working registers.

On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels set up at the data (D) inputs. A buffered output-enable ( $\overline{OE}$ ) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components.  $\overline{OE}$  does not affect internal operations of the latch.

Old data can be retained or new data can be entered while the outputs are in the high-impedance state. To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for partial-power-down applications using loff. The loff circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The output of the device is unknown until the first valid rising clock edge occurs while  $V_{CC}$  is within the Section 6.3 range.

### 8.2 Functional Block Diagram



To Seven Other Channels

Figure 8-1. Logic Diagram (Positive Logic)

#### 8.3 Feature Description

The device's wide operating range allows it to be used in a variety of systems that use different logic levels. The low propagation delay allows fast switching and higher speeds of operation. In addition, the low ground bounce stabilizes the performance of non-switching outputs while another output is switching.

#### 8.4 Device Functional Modes

Table 8-1 lists the functional modes of the SN74LV374A devices.

INPUTS										
CLK	D	Q								
↑ (	Н	Н								
↑	L	L								
L	Х	Q <sub>0</sub>								
Х	Х	Z								
	INPUTS	INPUTS								

#### Table 8-1. Function Table (Each Flip-Flop)



### 9 Application and Implementation

#### Note

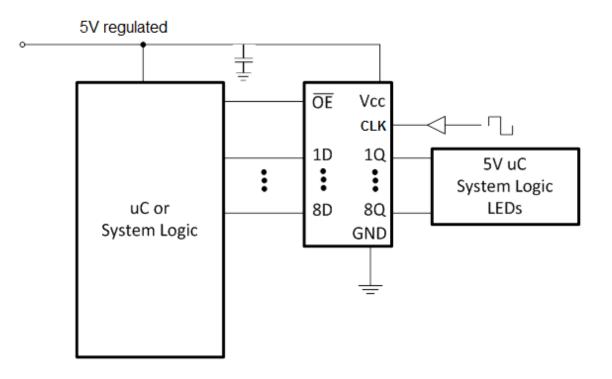
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

#### 9.1 Application Information

The SN74LV374A is a low drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs accept voltages up to 5.5 V allowing down translation to the  $V_{CC}$  level.

#### 9.2 Typical Application

Figure 9-1 shows how the slower edges can reduce ringing on the output compared to higher drive parts like AC.



#### Figure 9-1. Typical Application Schematic

#### 9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so consider routing and load conditions to prevent ringing.



#### 9.2.2 Detailed Design Procedure

- Recommended Input conditions:
  - Rise time and fall time specs see ( $\Delta t/\Delta V$ ) in Section 6.3.
  - Specified High and low levels. See ( $V_{IH}$  and  $V_{IL}$ ) in Section 6.3.
  - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V\_{CC}.
- Recommended output conditions:
  - Load currents should not exceed 35 mA per output and 70 mA total for the part.
  - Outputs should not be pulled above V<sub>CC</sub>.

#### 9.2.3 Application Curve

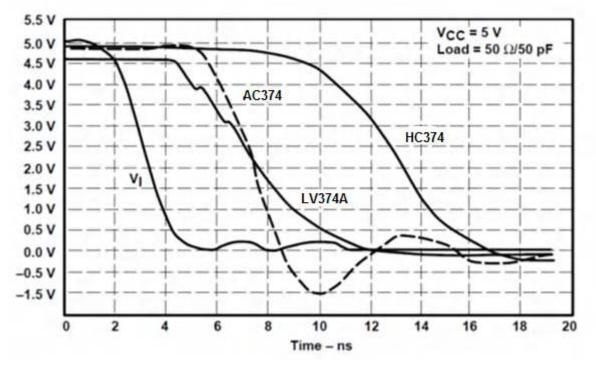


Figure 9-2. Switching Characteristics Comparison

### 9.3 Power Supply Recommendations

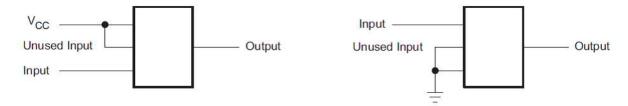
### 9.4 Layout

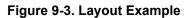
#### 9.4.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only three of the four buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$  whichever make more sense or is more convenient. Floating outputs is generally acceptable, unless the part is a transceiver. If the transceiver has an output enable pin it will disable the outputs section of the part when asserted. This will not disable the input section of the I.O's so they also cannot float when disabled.



#### 9.4.1.1 Layout Example







### **10 Device and Documentation Support**

#### **10.1 Documentation Support**

#### 10.1.1 Related Documentation

For related documentation see the following:

Implications of Slow or Floating CMOS Inputs, SCBA004

#### **10.2 Receiving Notification of Documentation Updates**

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### **10.3 Support Resources**

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 10.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments. All trademarks are the property of their respective owners.

## 10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.



## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



### PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins	Package	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
SN74LV374ADBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV374A	Samples
SN74LV374ADWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV374A	Samples
SN74LV374ANSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV374A	Samples
SN74LV374APWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV374A	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## PACKAGE OPTION ADDENDUM

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN74LV374A :

• Automotive : SN74LV374A-Q1

• Enhanced Product : SN74LV374A-EP

#### NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications



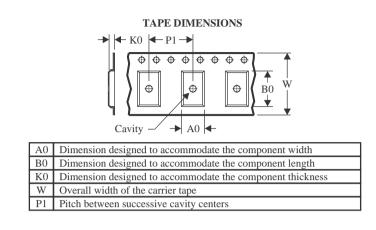
Texas

\*All dimensions are nominal

STRUMENTS

### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV374ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LV374ADWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LV374ANSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LV374APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



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## PACKAGE MATERIALS INFORMATION

12-May-2023



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV374ADBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74LV374ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LV374ANSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LV374APWR	TSSOP	PW	20	2000	356.0	356.0	35.0

## **DW0020A**



## **PACKAGE OUTLINE**

## SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



## DW0020A

## **EXAMPLE BOARD LAYOUT**

## SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

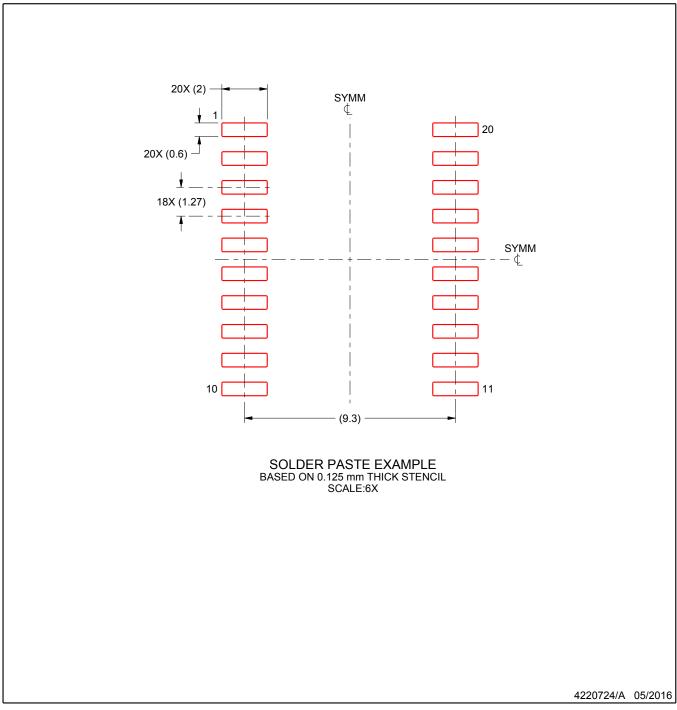


## DW0020A

## **EXAMPLE STENCIL DESIGN**

## SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **PW0020A**



## **PACKAGE OUTLINE**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.

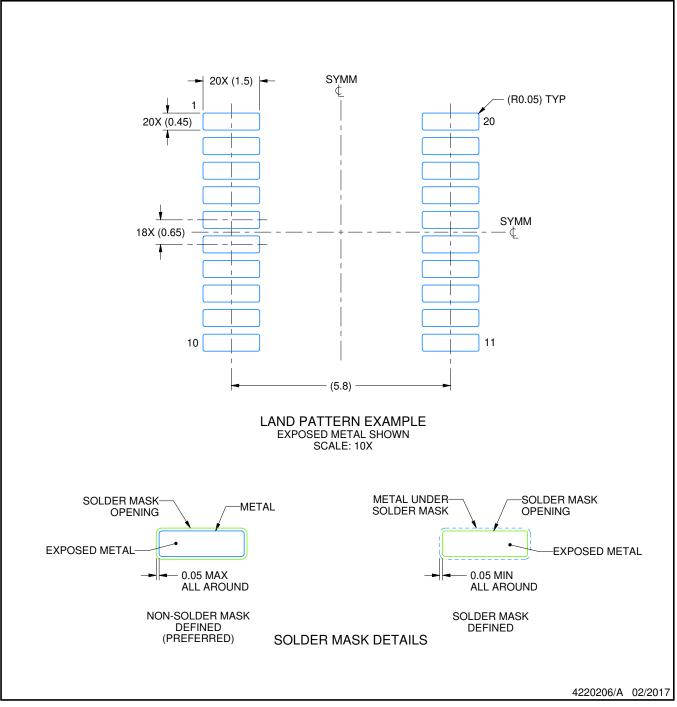


## PW0020A

## **EXAMPLE BOARD LAYOUT**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## PW0020A

# **EXAMPLE STENCIL DESIGN**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



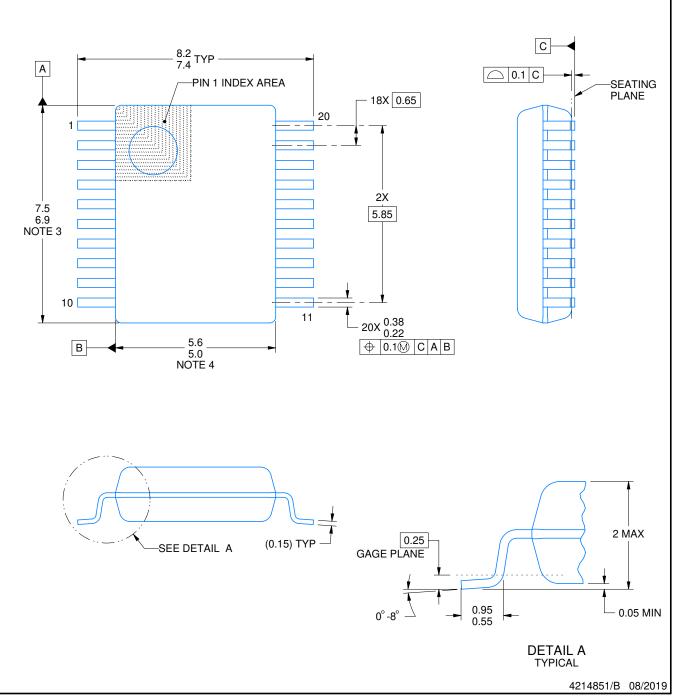
# **DB0020A**



## **PACKAGE OUTLINE**

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.

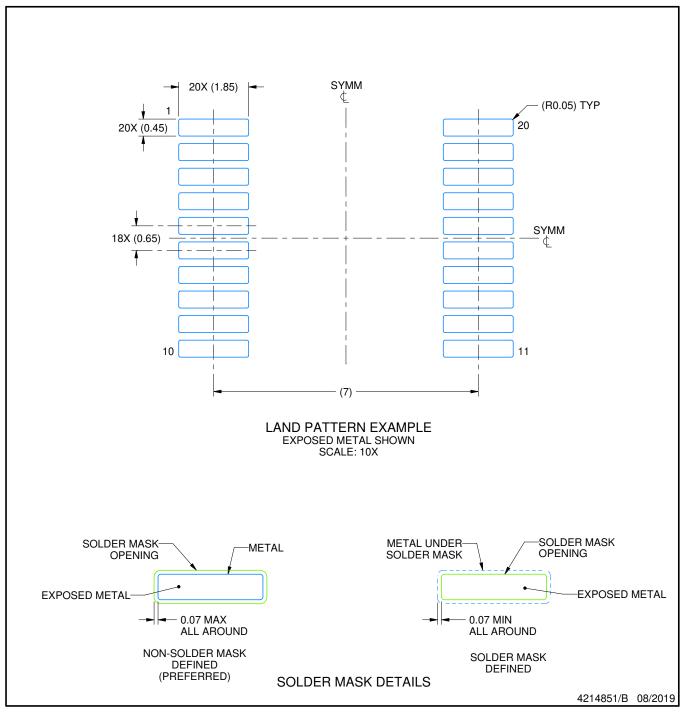


# DB0020A

# **EXAMPLE BOARD LAYOUT**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

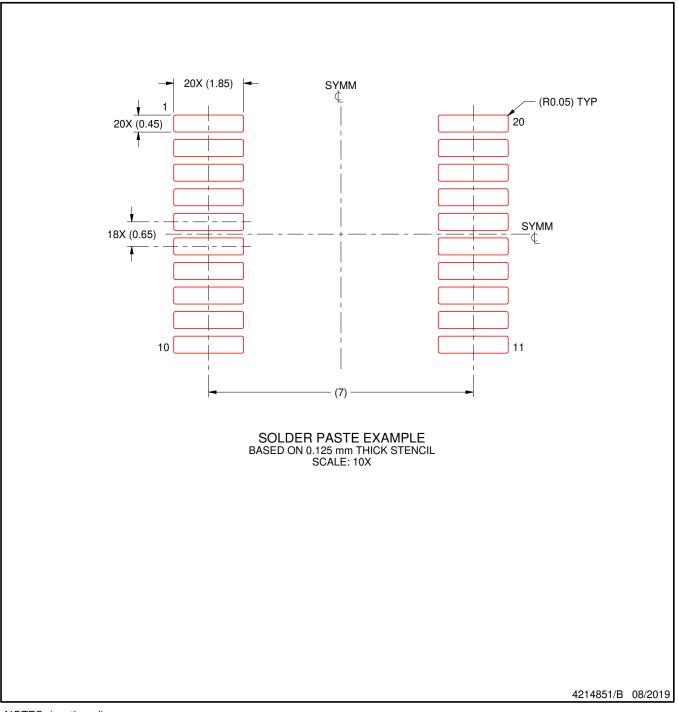


## DB0020A

# **EXAMPLE STENCIL DESIGN**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



### MECHANICAL DATA

#### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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